# MBRAF1100T3G

# **Schottky Power Rectifier**

## Surface Mount Power Package

Schottky Power Rectifiers employ the use of the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system. These state-of-the-art devices have the following features:

#### Features

- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- High Blocking Voltage 100 V
- 150°C Operating Junction Temperature
- Guardring for Stress Protection
- This is a Pb–Free Device

#### **Mechanical Characteristics**

- Case: Epoxy, Molded
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 12 mm Tape and Reel, 5000 Units per Reel
- Cathode Polarity Band

#### MAXIMUM RATINGS

| Rating   | Symbol   | Value       | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                         | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 100         | V    |
| Average Rectified Forward Current $T_L = 130^{\circ}C$   | I <sub>F(AV)</sub>                                     | 1.0         | A    |
| Non–Repetitive Peak Surge Current<br>(Surge Applied at Rated Load Conditions<br>Halfwave, Single Phase, 60 Hz) | I <sub>FSM</sub>                                       | 50          | A    |
| Operating Junction Temperature (Note 1)  | TJ   | -65 to +150 | °C   |
| Voltage Rate of Change   | dv/dt  | 10          | V/ns |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .



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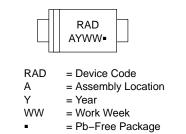
www.onsemi.com

### SCHOTTKY BARRIER RECTIFIER 1.0 AMPERE 100 VOLTS



SMA-FL CASE 403AA STYLE 6

#### MARKING DIAGRAM



#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## MBRAF1100T3G

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol | Value    | Unit |
|---|--------|----------|------|
| Thermal Resistance, Junction-to-Lead (Note 2)<br>Thermal Resistance, Junction-to-Ambient (Note 2) |        | 25<br>90 | °C/W |

2. 1 inch square pad size  $(1 \times 0.5 \text{ inch})$  for each lead on FR4 board.

#### **ELECTRICAL CHARACTERISTICS**

| Rating  | Symbol         | Value      | Unit |
|---|----------------|------------|------|
| Maximum Instantaneous Forward Voltage (Note 4) ( $i_F$ = 1.0 A, $T_J$ = 25°C)   | V <sub>F</sub> | 0.75       | V    |
| Maximum Instantaneous Reverse Current (Note 4)<br>(Rated dc Voltage, $T_J = 25^{\circ}C$ )<br>(Rated dc Voltage, $T_J = 100^{\circ}C$ ) |                | 0.5<br>5.0 | mA   |

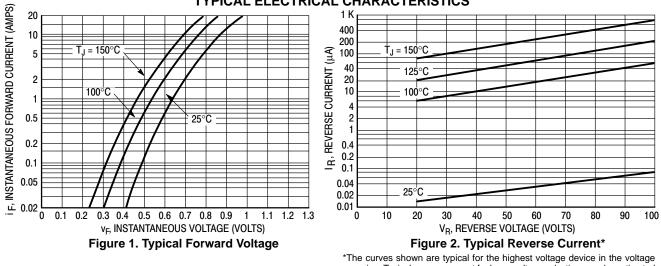
3. 1 inch square pad size  $(1 \times 0.5 \text{ inch})$  for each lead on FR4 board.

4. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

#### **ORDERING INFORMATION**

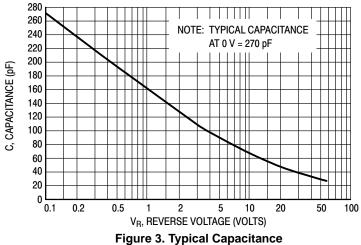
| Device       | Marking | Package             | Shipping <sup>†</sup> |
|--------------|---------|---------------------|-----------------------|
| MBRAF1100T3G | RAD     | SMA-FL<br>(Pb-Free) | 5000 / Tape & Reel    |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



### **TYPICAL ELECTRICAL CHARACTERISTICS**

grouping. Typical reverse current for lower voltage selections can be estimated from these curves if V<sub>R</sub> is sufficient below rated V<sub>R</sub>.



## MBRAF1100T3G

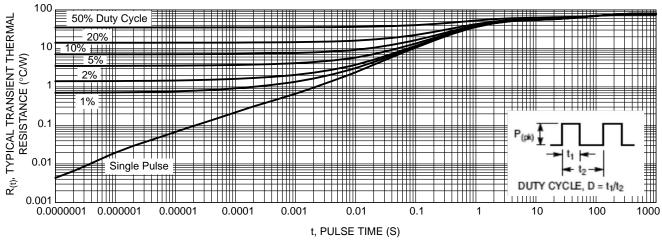


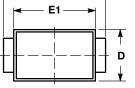
Figure 4. Typical Transient Thermal Response, Junction-to-Ambient



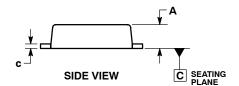


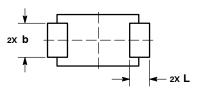
SMA-FL CASE 403AA-01 ISSUE O





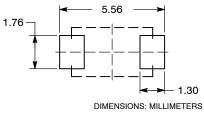






**BOTTOM VIEW** 

#### RECOMMENDED SOLDER FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|---|---|--|-------------|
| DESCRIPTION:  | SMA-FL  |  | PAGE 1 OF 1 |
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DATE 02 MAR 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

|     | MILLIMETERS |      |  |
|-----|-------------|------|--|
| DIM | MIN         | MAX  |  |
| Α   | 0.90        | 1.10 |  |
| b   | 1.25        | 1.65 |  |
| С   | 0.15        | 0.30 |  |
| D   | 2.40        | 2.80 |  |
| E   | 4.80        | 5.40 |  |
| E1  | 4.00        | 4.60 |  |
| L   | 0.70        | 1.10 |  |

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